

FRED**Ultrafast Soft Recovery Diode, 1200V, 75A****Description:**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery character of the diodes offers buffer in most applications. These devices are suited for power converters and other applications where the switching losses are not significant portion of the total losses.

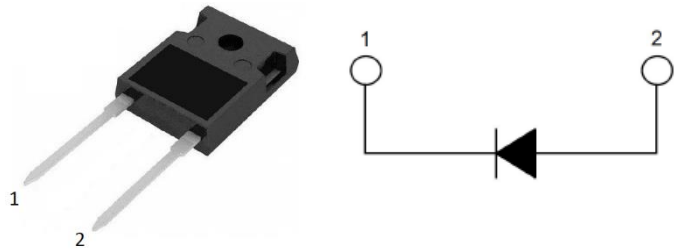
Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low IR value
- High surge capacity
- Epitaxial chip construction

Product Summary	
V_R	1200 V
$I_{F(AV)}$	75 A
t_{rr}	55 ns

Applications:

- Switched mode power supply
- Free wheeling diode, Snubber diode
- UPS

**Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	V_{RRM}		1200	V
Continuous forward current	$I_{F(AV)}$	$T_A=110^{\circ}\text{C}$	75	A
Single pulse forward current	I_{FSM}	$T_A=25^{\circ}\text{C}$	520	A
Maximum repetitive forward current	I_{FRM}	Square wave, 20kHz	150	A
Operating junction	T_j		175	$^{\circ}\text{C}$
Storage temperatures	T_{stg}		-55 to +175	$^{\circ}\text{C}$

Electrical characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Breakdown voltage	V_{BR}	$I_R=100\mu\text{A}$	1200			V
Blocking voltage	V_R					
Forward voltage	V_F	$I_F=75\text{ A}$		2.00	2.80	V
		$I_F=75\text{ A}, T_j=125^{\circ}\text{C}$		1.75	2.60	V
Reverse leakage current	I_R	$V_R=V_{RRM}$			60	μA
		$T_j=150^{\circ}\text{C}, V_R=1200\text{V}$			600	μA
Reverse recovery time	t_{rr}	$I_F=0.5\text{A}, I_R=1\text{A}, I_{RR}=0.25\text{A}$			100	ns
		$I_F=1\text{A}, V_R=30\text{V}, di/dt=200\text{A}/\mu\text{s}$		45	55	ns

Thermal characteristics

Parameter	Symbol	Typ	MAX	Units
Junction-to-Case	R_{thJC}	-	0.70	$^{\circ}\text{C}/\text{W}$

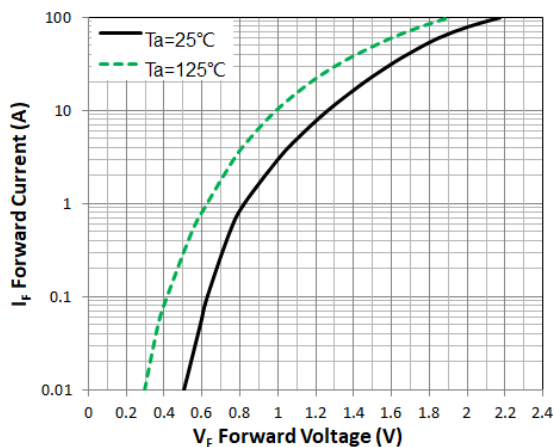


Figure 1. Forward Characteristic(typ.)

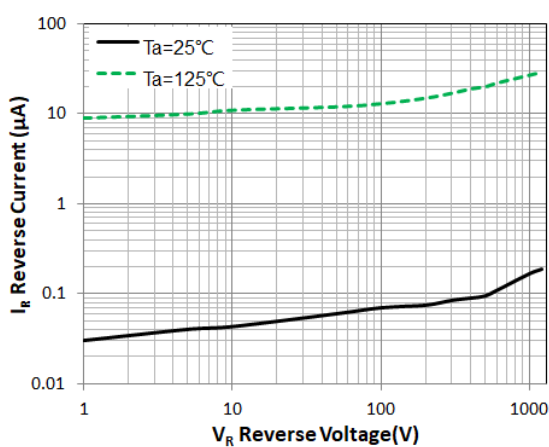
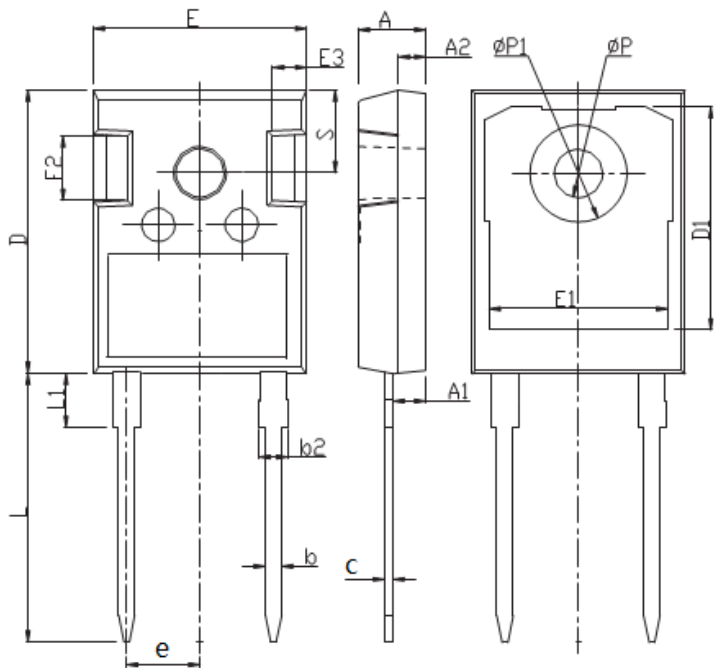


Figure 2. Reverse Characteristic(typ.)

Package Information

TO-247-2 PACKAGE



Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.10	1.30
b2	1.90	2.15
c	0.50	0.75
D	20.70	21.30
D1	16.25	16.85
e	5.25	5.65
E	15.60	16.00
E1	13.06	13.46
E2	4.80	5.20
E3	1.80	2.50
L	19.62	20.22
L1	4.00	4.30
ΦP	3.40	3.80
$\Phi P1$	7.00	7.30
S	5.95	6.35